# PDTC143X series

NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$ 

Rev. 11 — 9 December 2011

**Product data sheet** 

## 1. Product profile

### 1.1 General description

NPN Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package			PNP	Package
	NXP	JEITA	JEDEC	complement	configuration
PDTC143XE	SOT416	SC-75	-	PDTA143XE	ultra small
PDTC143XM	SOT883	SC-101	-	PDTA143XM	leadless ultra small
PDTC143XT	SOT23	-	TO-236AB	PDTA143XT	small
PDTC143XU	SOT323	SC-70	-	PDTA143XU	very small

#### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

### 1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
Io	output current		-	-	100	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	$k\Omega$
R2/R1	bias resistor ratio		1.7	2.1	2.6	



# 2. Pinning information

Table 3. **Pinning** Simplified outline **Graphic symbol** Pin Description SOT23; SOT323; SOT416 1 input (base) 3 2 GND (emitter) 3 output (collector) 006aaa144 sym007 **SOT883** 1 input (base) 2 GND (emitter) output (collector) Transparent

# 3. Ordering information

Table 4. Ordering information

PDTC143XE	Name	Description	1
PDTC143XE		Description	Version
	SC-75	plastic surface-mounted package; 3 leads	SOT416
PDTC143XM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883
PDTC143XT	-	plastic surface-mounted package; 3 leads	SOT23
PDTC143XU	SC-70	plastic surface-mounted package; 3 leads	SOT323

# 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
PDTC143XE	34
PDTC143XM	E2
PDTC143XT	*32
PDTC143XU	*53

[1] \* = placeholder for manufacturing site code

# 5. Limiting values

Table 6. Limiting values

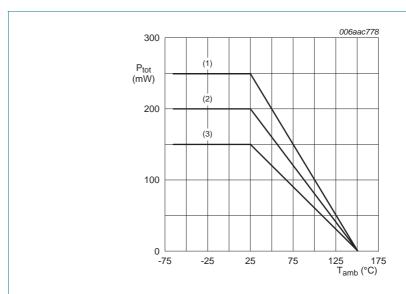
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	50	V
$V_{CEO}$	collector-emitter voltage	open base	-	50	V
$V_{EBO}$	emitter-base voltage	open collector	-	7	V
VI	input voltage				
	positive		-	+20	V
	negative		-	<b>-7</b>	V
I <sub>O</sub>	output current		-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	PDTC143XE (SOT416)		[1][2] _	150	mW
	PDTC143XM (SOT883)		[2][3]	250	mW
	PDTC143XT (SOT23)		[1] -	250	mW
	PDTC143XU (SOT323)		[1] -	200	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 PCB with 70  $\mu m$  copper strip line, standard footprint.



- (1) SOT23; FR4 PCB, standard footprint SOT883; FR4 PCB with 70  $\mu m$  copper strip line, standard footprint
- (2) SOT323; FR4 PCB, standard footprint
- (3) SOT416; FR4 PCB, standard footprint

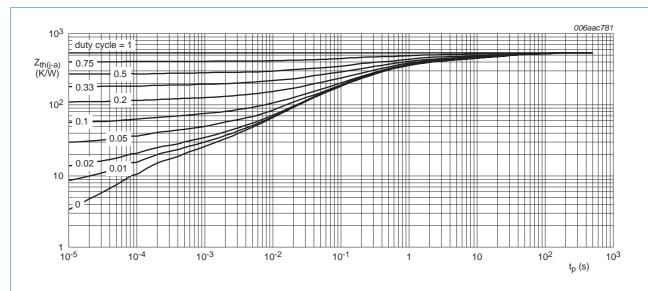
Fig 1. Power derating curves

### 6. Thermal characteristics

Table 7. Thermal characteristics

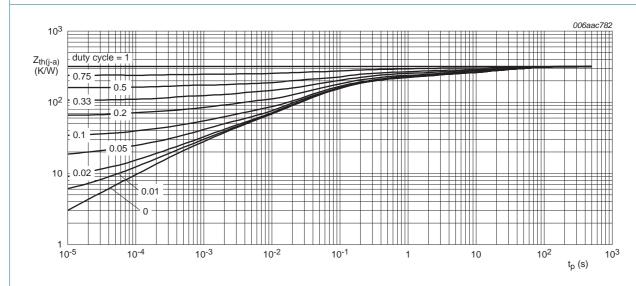
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	PDTC143XE (SOT416)		[1][2]	-	830	K/W
	PDTC143XM (SOT883)		[2][3]	-	500	K/W
	PDTC143XT (SOT23)		[1] -	-	500	K/W
	PDTC143XU (SOT323)		<u>[1]</u> _	-	625	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB with 70  $\mu m$  copper strip line, standard footprint.



FR4 PCB, standard footprint

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC143XE (SOT416); typical values



FR4 PCB, 70 µm copper strip line

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC143XM (SOT883); typical values

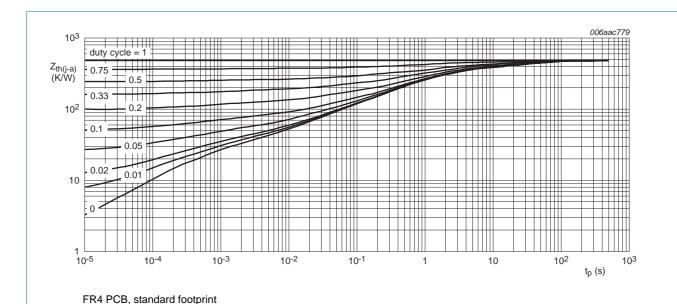


Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC143XT (SOT23); typical values

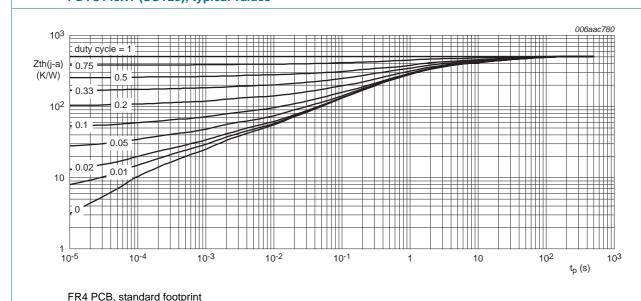


Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC143XU (SOT323); typical values

NPN resistor-equipped transistors; R1 = 4.7 kΩ, R2 = 10 kΩ

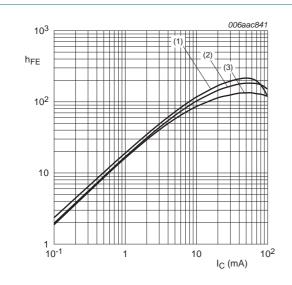
## 7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	1	μΑ
	cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	600	μΑ
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$	50	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	-	100	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$	-	0.9	0.3	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 20 \text{ mA}$	2.5	1.5	-	V
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		1.7	2.1	2.6	
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V; } I_{C} = 10 \text{ mA;}$ f = 100 MHz	<u>[1]</u> -	230	-	MHz

<sup>[1]</sup> Characteristics of built-in transistor



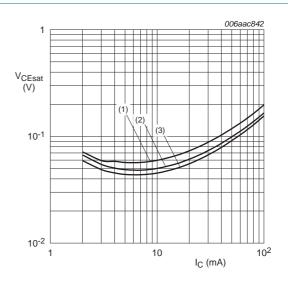
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 6. DC current gain as a function of collector current; typical values



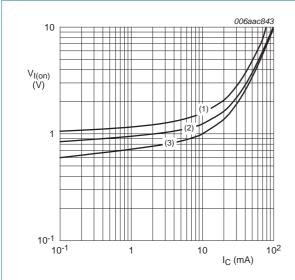
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values



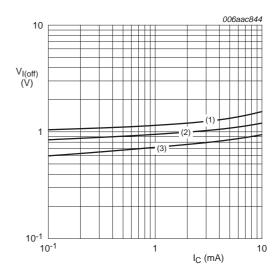
$$V_{CE} = 0.3 \text{ V}$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 8. On-state input voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 9. Off-state input voltage as a function of collector current; typical values

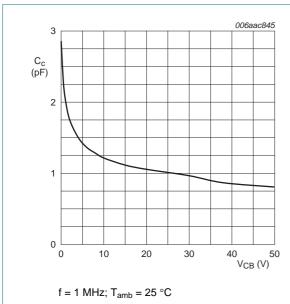


Fig 10. Collector capacitance as a function of collector-base voltage; typical values

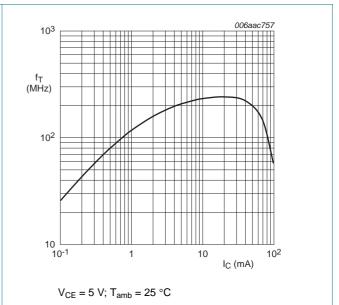


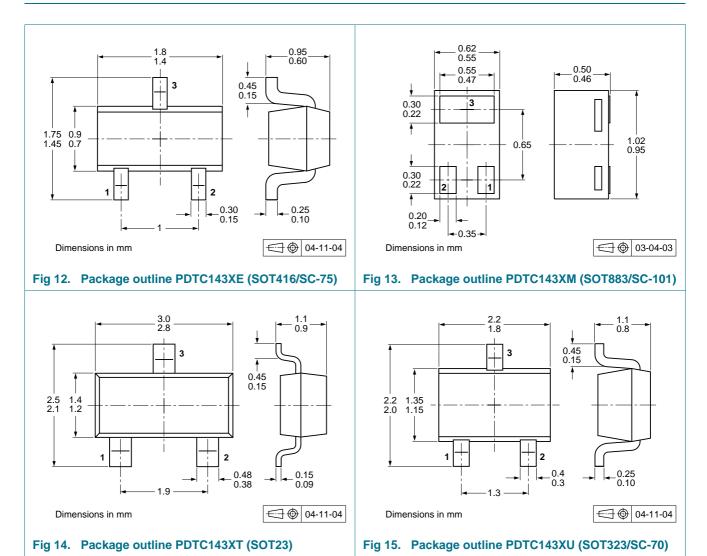
Fig 11. Transition frequency as a function of collector current; typical values of built-in transistor

### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



# 10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	ng quantity	
			3000	5000	10000
PDTC143XE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTC143XM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTC143XT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235
PDTC143XU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135

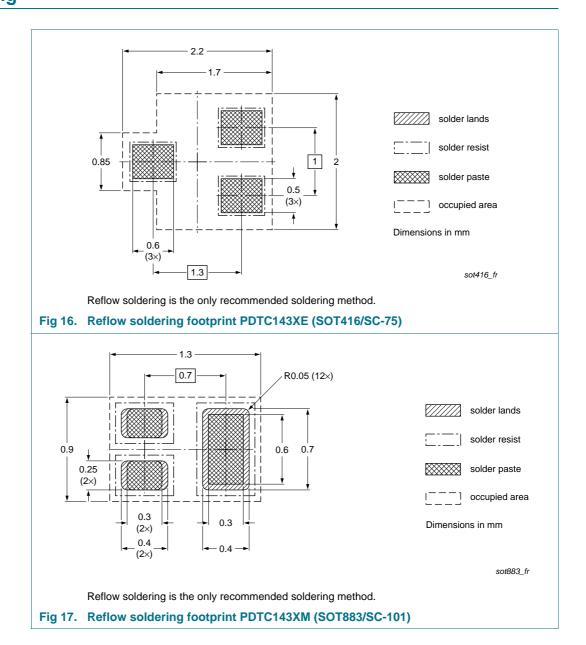
[1] For further information and the availability of packing methods, see Section 14.

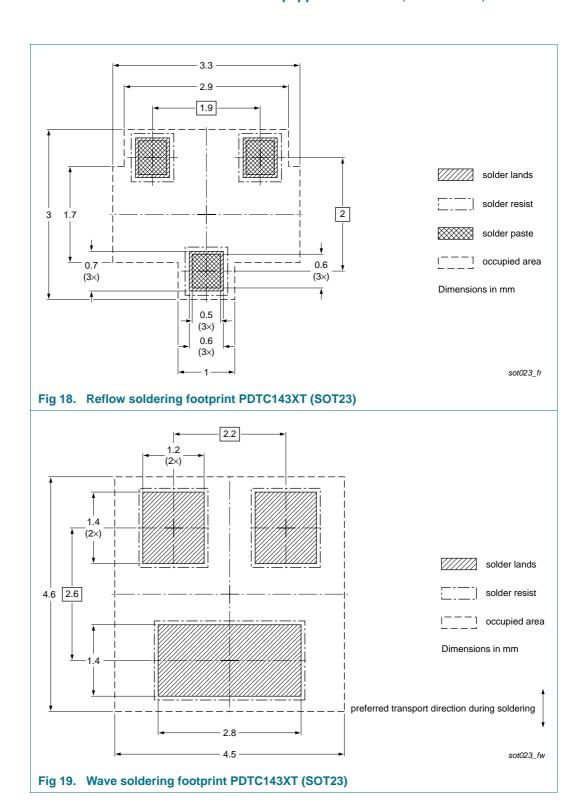
PDTC143X\_SER

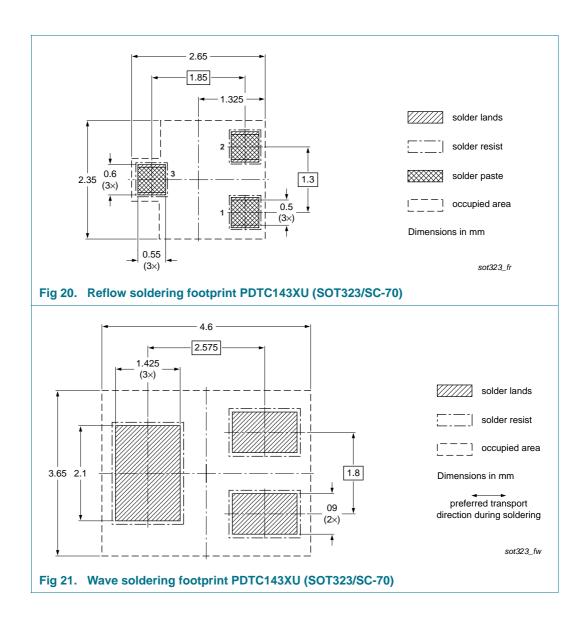
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## 11. Soldering







NPN resistor-equipped transistors; R1 = 4.7 kΩ, R2 = 10 kΩ

# 12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTC143X_SER v.11	20111209	Product data sheet	-	PDTC143X_SERIES v.10
Modifications:	<ul> <li>Type numbers</li> <li>Section 1 "Production 2" Piroduction 2" Piroduction 2" Piroduction 2" Piroduction 4" Material Section 4" Material 4" Additional 4" Pigure 1 to 5, Section 6" The Figure 6 to 9: Table 8 "Charate Section 8" Testion 8" Testion</li></ul>	s PDTC143XEF, PDTC143XI coduct profile": updated nning information": updated arking": updated 10 and 11: added ermal characteristics": update	ed	emoved.
	• Section 13 "L	egal information": updated		
PDTC143X_SERIES v.10	20091116	Product data sheet	-	PDTC143X_SERIES v.9
PDTC143X_SERIES v.9	20050726	Product data sheet	-	PDTC143X_SERIES v.8
PDTC143X_SERIES v.8	20040806	Product specification	-	PDTC143X_SERIES v.7
PDTC143X_SERIES v.7	20040323	Product specification	-	PDTC143X_SERIES v.6
PDTC143X_SERIES v.6	20040112	Product specification	-	PDTC143X_SERIES v.5
PDTC143X_SERIES v.5	20031112	Product specification	-	PDTC143X_SERIES v.4
PDTC143X_SERIES v.4	20030910	Product specification	-	PDTC143X_SERIES v.3
PDTC143X_SERIES v.3	20030410	Product specification	-	-

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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# PDTC143X series

NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$ 

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# PDTC143X series

NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$ 

## 15. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information
3	Ordering information
4	Marking 2
5	Limiting values 3
6	Thermal characteristics4
7	Characteristics 7
8	Test information
8.1	Quality information
9	Package outline
10	Packing information 10
11	Soldering 11
12	Revision history
13	Legal information
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks16
14	Contact information
15	Contents 17

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